Standard Recovery Diodes (Stud Version), 200 A

FEATURES

- Wide current range · High voltage ratings up to 2400 V
- High surge current capabilities · Stud cathode and stud anode version
- Standard JEDEC types
- Compression bonded encapsulations
- RoHS complaint
- · Lead (Pb)-free
- Designed and qualified for industrial level

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · Machine tool controls
- · High power drives
- · Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	SD200N/R		UNITS		
		1600 to 2000	2400	UNITS		
		200		A		
I _{F(AV)}	T _C	110		°C		
I _{F(RMS)}		314		A		
1	50 Hz	4700				
IFSM	60 Hz	4920				
l ² t	50 Hz	110 101		50 Hz 110		kA ² s
1-1	60 Hz			- кА²s		
V _{RRM}	Range	1600 to 2000	2400	V		
TJ		- 40 to 180	150	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA	
	16	1600	1700		
SD200N/R	20	2000	2100	15	
	24	2400	2500		

DO-205AC (DO-30)

PRODUCT SUMMARY 200 A I_{F(AV)}

Vishay High Power Products

SD200N/R Series









SD200N/R Series

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FORWARD CONDUCTION	l					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave		200	А	
at case temperature				110	°C	
Maximum average forward current	I _{F(AV)}			Too conduction, nan sine wave	220	А
at case temperature				100	°C	
Maximum RMS forward current	I _{F(RMS)}	DC at 95 °C case temperature		ature	314	
		t = 10 ms	No voltage		4700	
Maximum peak, one-cycle forward,	I _{FSM}	t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	4920	A
non-repetitive surge current		t = 10 ms	100 % V _{RRM}		3950	
		t = 8.3 ms	reapplied		4140	
	l ² t	t = 10 ms	No voltage reapplied		110	- kA ² s
Manimum 124 fau funcin a		t = 8.3 ms			101	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		78	
		t = 8.3 ms	reapplied		71	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		1100	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.90	v	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		1.00		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.79		
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		0.64	- mΩ	
Maximum forward voltage drop	V _{FM}	$I_{pk} = 630 \text{ A}, T_J = T_J \text{ maximum},$ $t_p = 10 \text{ ms sinusoidal wave}$		1.40	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	SD20		
	STMBOL	TEST CONDITIONS	1600 to 2000	2400	UNITS
Maximum junction operating temperature range	TJ	Г _Ј - 40 to 18		- 40 to 150	°C
Maximum storage temperature range	T _{Stg}	- 55 to 200		200	
Maximum thermal resistance, junction to case	R _{thJC} DC operation 0.23		K/W		
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.08		rv vv
Maximum allowed mounting torque ± 10 %		Not-lubricated threads	14		Nm
Approximate weight			120		g
Case style		See dimensions (link at the end of datasheet)	DO-205AC (DO-30)		

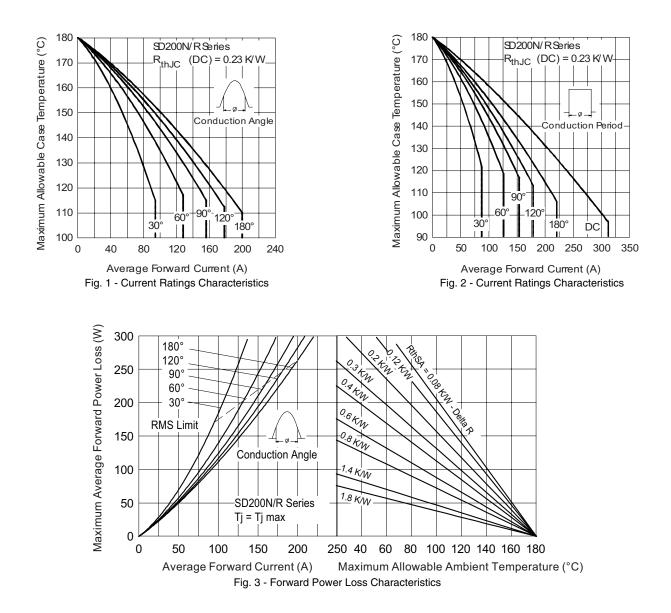


Standard Recovery Diodes Vishay High Power Products (Stud Version), 200 A

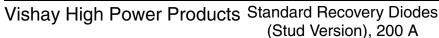
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.041	0.030				
120°	0.049	0.051				
90°	0.063	0.068	$T_J = T_J maximum$	K/W		
60°	0.093	0.096				
30°	0.156	0.157				

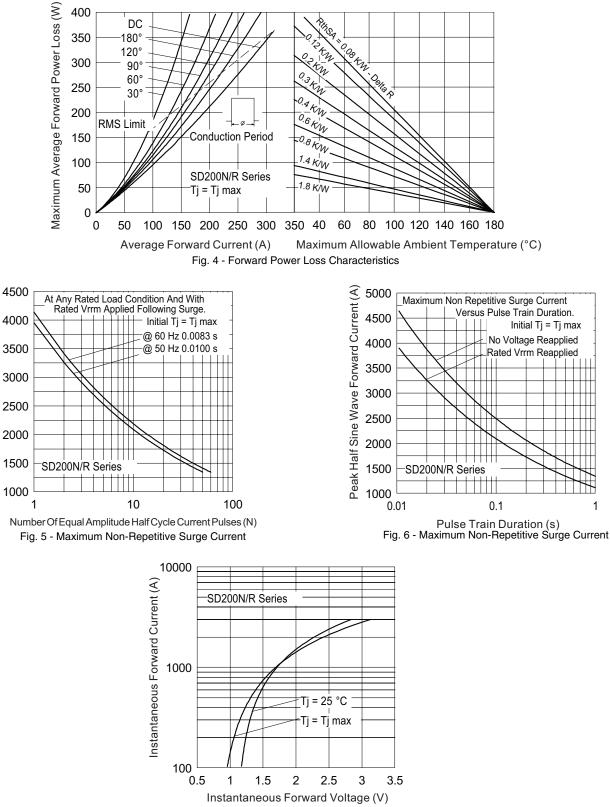
Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

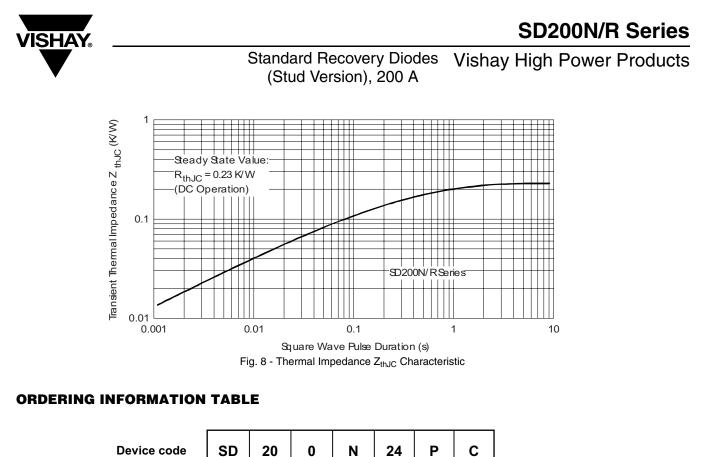


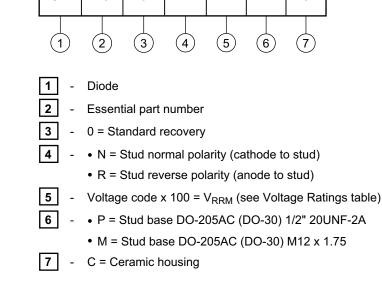
SD200N/R Series





Peak Half Sine Wave Forward Current (A)





For metric device M12 x 1.75 contact factory

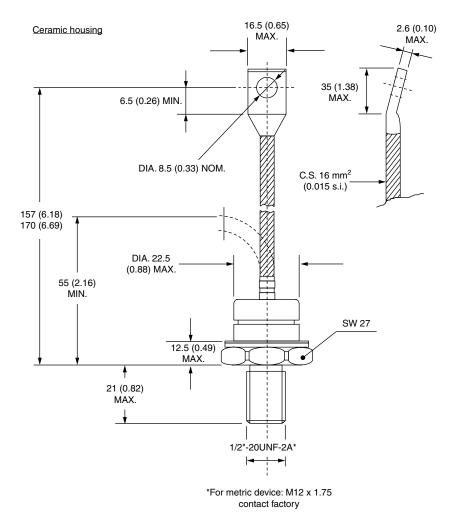
LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95302			

Vishay Semiconductors



DO-205AC (DO-30)

DIMENSIONS in millimeters (inches)





Vishay

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